

ON Semiconductor®

ON Semiconductor DATA SHEET

2SK3818— R-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.
- · Motor drive, DC / DC converter.
- · Avalanche resistance guarantee.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		74	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	296	Α
Allowable Power Dissipation	D-		1.65	W
	PD	Tc=25°C	75	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Enargy (Single Pulse) *1	EAS		410	mJ
Avalanche Current *2	IAV		74	А

Note: *1 V_{DD}=20V, L=100μH, I_{AV}=74A

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} = ±16V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =37A	27	45		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =37A, V _G S=10V		10	13	mΩ
	R _{DS} (on)2	I _D =37A, V _G S=4V		13	18	mΩ

Marking: K3818 Continued on next page.

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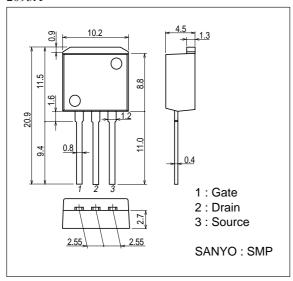
^{*2} L≤100µH, single pulse

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		5250		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		780		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		525		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		38		ns
Rise Time	t _r	See specified Test Circuit.		315		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		370		ns
Fall Time	tf	See specified Test Circuit.		310		ns
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =10V, I _D =74A		100		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =74A		18		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =10V, I _D =74A		16		nC
Diode Forward Voltage	V _{SD}	I _S =74A, V _{GS} =0		1.13	1.5	V

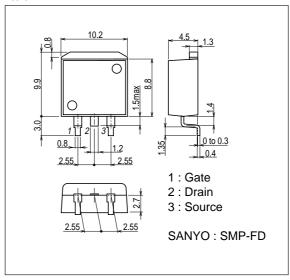
Package Dimensions

unit: mm 2093A

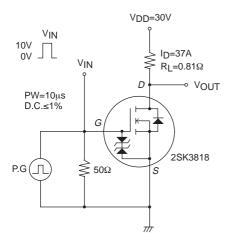


Package Dimensions

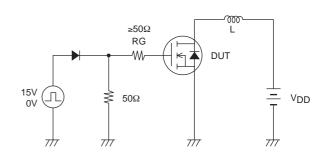
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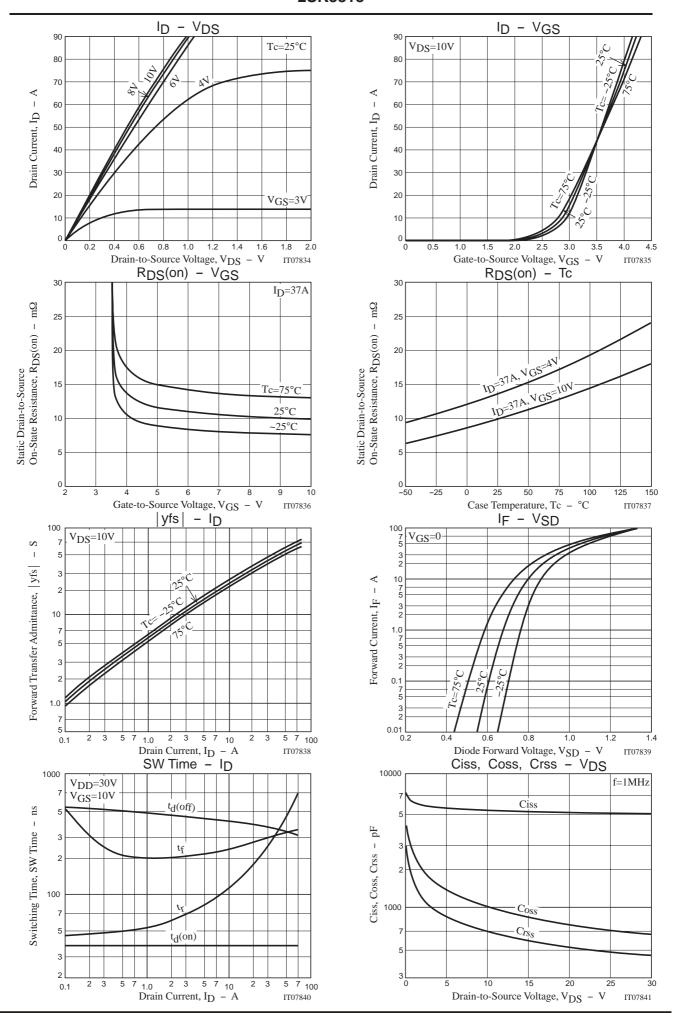


Switching Time Test Circuit

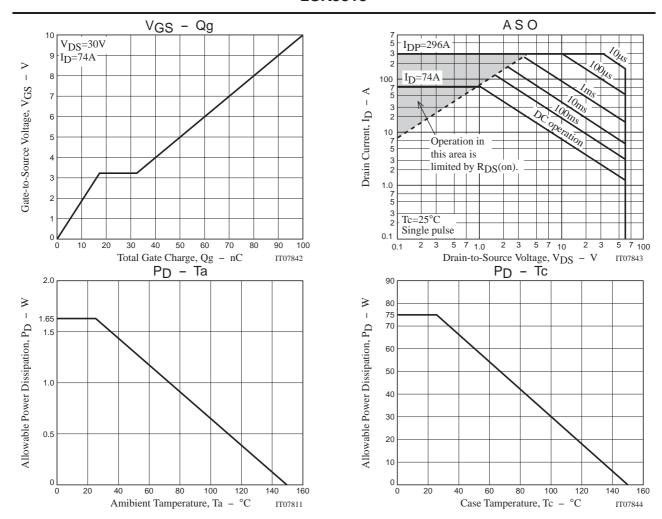


Unclamped Inductive Test Circuit





2SK3818



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